

DS42BR400 Quad 4.25 Gbps CML Transceiver with Transmit **De-Emphasis and Receive Equalization**

Check for Samples: DS42BR400

FEATURES

- 250 Mbps 4.25 Gbps Fully Differential Data
- **Optional Fixed Input Equalization**
- Selectable Output De-emphasis
- **Individual Loopback Controls**
- **On-Chip Termination**
- Lead-less WQFN-60 Pin Package (9 mm x 9 mm x 0.8 mm, 0.5 mm Pitch)
- -40°C to +85°C Industrial Temperature Range
- 6 kV ESD Rating, HBM

APPLICATIONS

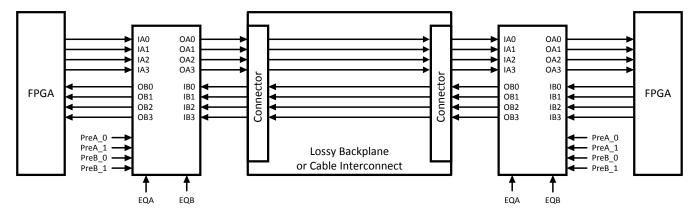
- **Backplane Driver or Cable Driver**
- Signal Repeating, Buffering and Conditioning **Applications**

DESCRIPTION

The DS42BR400 is a quad 250 Mbps - 4.25 Gbps CML transceiver, or 8-channel buffer, for use in backplane and cable applications. With operation down to 250 Mbps, the DS42BR400 can be used in applications requiring both low and high frequency data rates. Each input stage has a fixed equalizer to reduce ISI distortion from board traces. The equalizers are grouped in fours and are enabled through two control pins. These control pins provide customers flexibility where ISI distortion may vary from one direction to another.

All output drivers have four selectable steps of deemphasis to compensate against transmission loss across long FR4 backplanes. The de-emphasis blocks are also grouped in fours. In addition, the DS42BR400 also has loopback control capability on four channels. All CML drivers have 50Ω termination to V_{CC}. All receivers are internally terminated with differential 100Ω .

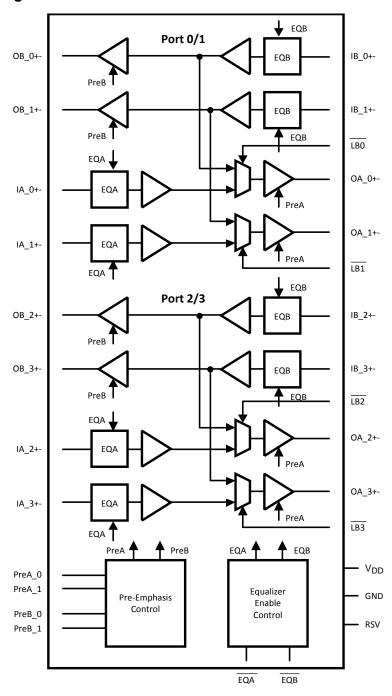
Simplified Application Diagram



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Functional Block Diagram





Connection Diagram

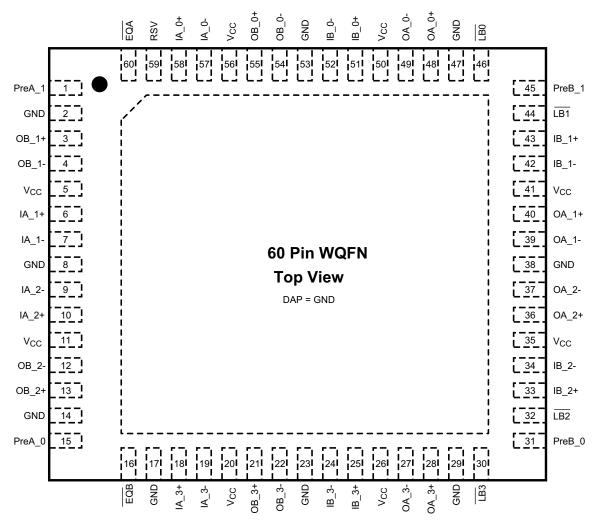


Figure 1. Leadless WQFN-60 Pin Package (9 mm x 9 mm x 0.8 mm, 0.5 mm pitch)
See Package Number NKA0060A

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PIN DESCRIPTIONS

PIN DESCRIPTIONS										
Pin Name	Pin Number	I/O ⁽¹⁾	Description							
DIFFERENTIA	AL I/O									
IB_0+ IB_0-	51 52	I	Inverting and non-inverting differential inputs of port_0. IB_0+ and IB_0- are internally connected to a reference voltage through a 50Ω resistor. Refer to Figure 8.							
OA_0+ OA_0-	48 49	0	Inverting and non-inverting differential outputs of port_0. OA_0+ and OA_0- are connected to V_{CC} through a 50Ω resistor.							
IB_1+ IB_1-	43 42	_	Inverting and non-inverting differential inputs of port_1. IB_1+ and IB_1- are internally connected to a reference voltage through a 50Ω resistor. Refer to Figure 8.							
OA_1+ OA_1-	40 39	0	Inverting and non-inverting differential outputs of port_1. OA_1+ and OA_1- are connected to V_{CC} through a 50Ω resistor.							
IB_2+ IB_2-	33 34	I	Inverting and non-inverting differential inputs of port_2. IB_2+ and IB_2- are internally connected to a reference voltage through a 50Ω resistor. Refer to Figure 8.							
OA_2+ OA_2-	36 37	0	Inverting and non-inverting differential outputs of port_2. OA_2+ and OA_2- are connected to V_{CC} through a 50Ω resistor.							
IB_3+ IB_3-	25 24	I	Inverting and non-inverting differential inputs of port_3. IB_3+ and IB_3- are internally connected to a reference voltage through a 50Ω resistor. Refer to Figure 8.							
OA_3+ OA_3-	28 27	0	Inverting and non-inverting differential outputs of port_3. OA_3+ and OA_3- are connected to V_{CC} through a 50Ω resistor.							
IA_0+ IA_0-	58 57	I	Inverting and non-inverting differential inputs of port_0. IA_0+ and IA_0- are internally connected to a reference voltage through a 50Ω resistor. Refer to Figure 8.							
OB_0+ OB_0-	55 54	0	Inverting and non-inverting differential outputs of port_0. OB_0+ and OB_0- are connected to V_{CC} through a 50Ω resistor.							
IA_1+ IA_1-	6 7	I	Inverting and non-inverting differential inputs of port_1. IA_1+ and IA_1- are internally connected to a reference voltage through a 50Ω resistor. Refer to Figure 8.							
OB_1+ OB_1-	3 4	0	Inverting and non-inverting differential outputs of port_1. OB_1+ and OB_1- are connected to V_{CC} through a 50Ω resistor.							
IA_2+ IA_2-	10 9	I	Inverting and non-inverting differential inputs of port_2. IA_2+ and IA_2- are internally connected to a reference voltage through a 50Ω resistor. Refer to Figure 8.							
OB_2+ OB_2-	13 12	0	Inverting and non-inverting differential outputs of port_2. OB_2+ and OB_2- are connected to V_{CC} through a 50Ω resistor.							
IA_3+ IA_3-	18 19	I	Inverting and non-inverting differential inputs of port_3. IA_3+ and IA_3- are internally connected to a reference voltage through a 50Ω resistor. Refer to Figure 8.							
OB_3+ OB_3-	21 22	0	Inverting and non-inverting differential outputs of port_3. OB_3+ and OB_3- are connected to V_{CC} through a 50Ω resistor.							
CONTROL (3	3V LVCMOS)									
EQA	60	I	This pin is active LOW. A logic LOW at $\overline{\text{EQA}}$ enables equalization for input channels IA_0±, IA_1±, IA_2±, and IA_3±. By default, this pin is internally pulled high and equalization is disabled.							
EQB	16	I	This pin is active LOW. A logic LOW at $\overline{\text{EQB}}$ enables equalization for input channels IB_0±, IB_1±, IB_2±, and IB_3±. By default, this pin is internally pulled high and equalization is disabled.							
PreA_0 PreA_1	15 1	I	PreA_0 and PreA_1 select the output de-emphasis levels (OA_0±, OA_1±, OA_2±, and OA_3±). PreA_0 and PreA_1 are internally pulled high. Please see Table 2 for de-emphasis levels.							
PreB_0 PreB_1	31 45	I	PreB_0 and PreB_1 select the output de-emphasis levels (OB_0±, OB_1±, OB_2±, and OB_3±). PreB_0 and PreB_1 are internally pulled high. Please see Table 2 for de-emphasis levels.							
LB0	46	I	This pin is active LOW. A logic LOW at $\overline{LB0}$ enables the internal loopback path from IB_0± to OA_0±. $\overline{LB0}$ is internally pulled high. Please see Table 1 for more information.							
LB1	44	I	This pin is active LOW. A logic LOW at $\overline{LB1}$ enables the internal loopback path from IB_1± to OA_1±. LB1 is internally pulled high. Please see Table 1 for more information.							
LB2	32	I	This pin is active LOW. A logic LOW at $\overline{LB2}$ enables the internal loopback path from IB_2± to OA_2±. $\overline{LB2}$ is internally pulled high. Please see Table 1 for more information.							
LB3	30	I	This pin is active LOW. A logic LOW at $\overline{LB3}$ enables the internal loopback path from IB_3± to OA_3±. $\overline{LB3}$ is internally pulled high. Please see Table 1 for more information.							
RSV	59	I	Reserve pin to support factory testing. This pin can be left open, tied to GND, or tied to GND through an external pull-down resistor.							

(1) Note: I = Input, O = Output, P = Power



PIN DESCRIPTIONS (continued)

Pin Name	Pin Number	I/O ⁽¹⁾	Description
POWER			
V _{CC}	5, 11, 20, 26, 35, 41, 50, 56	Р	V_{CC} = 3.3V ± 5%. Each V_{CC} pin should be connected to the V_{CC} plane through a low inductance path, typically with a via located as close as possible to the landing pad of the V_{CC} pin. It is recommended to have a 0.01 μF or 0.1 μF, X7R, size-0402 bypass capacitor from each V_{CC} pin to ground plane.
GND	2, 8, 14, 17, 23, 29, 38, 47, 53	Р	Ground reference. Each ground pin should be connected to the ground plane through a low inductance path, typically with a via located as close as possible to the landing pad of the GND pin.
GND	DAP	Р	DAP is the metal contact at the bottom side, located at the center of the WQFN-60 pin package. It should be connected to the GND plane with at least 4 via to lower the ground impedance and improve the thermal performance of the package.

Functional Description

Table 1. Logic Table for Loopback Controls

LB0	Loopback Function					
0	Enable loopback from IB_0± to OA_0±.					
1 (default)	Normal mode. Loopback disabled.					
LB1	Loopback Function					
0	Enable loopback from IB_1± to OA_1±.					
1 (default)	Normal mode. Loopback disabled.					
LB2	Loopback Function					
0	Enable loopback from IB_2± to OA_2±.					
1 (default)	Normal mode. Loopback disabled.					
LB3	Loopback Function					
0	Enable loopback from IB_3± to OA_3±.					
1 (default)	Normal mode. Loopback disabled.					

Table 2. De-Emphasis Controls

PreA_[1:0]	Default VOD Level in mV _{PP} (VODB)	De-Emphasis Level in mV _{PP} (VODPE)	De-Emphasis in dB (VODPE/VODB)
0 0	1200	1200	0
0 1	1200	850	-3
10	1200	600	-6
1 1 (Default)	1200	426	-9
PreB_[1:0]	Default VOD Level in mV _{PP} (VODB)	De-Emphasis Level in mV _{PP} (VODPE)	De-Emphasis in dB (VODPE/VODB)
0 0	1200	1200	0
0 1	1200	850	-3
1 0	1200	600	-6
1 1 (Default)	1200	426	-9



De-emphasis is the primary signal conditioning function for use in compensating against backplane transmission loss. The DS42BR400 provides four steps of de-emphasis ranging from 0, -3, -6 and -9 dB, user-selectable dependent on the loss profile of the backplane. Figure 2 shows a driver de-emphasis waveform. The de-emphasis duration is nominal 200 ps, corresponding to 85% bit-width at 4.25 Gbps.

The high speed inputs are self-biased to about 1.3V and are designed for AC coupling allowing the DS42BR400 to be directly inserted into the datapath without any limitation. The ideal AC coupling capacitor value is often based on the lowest frequency component embedded within the serial link. A typical AC coupling capacitor value rages between 100 and 1000nF, some specifications with scrambled data may require a larger coupling capacitor for optimal performance. To reduce unwanted parasitics around and within the AC coupling capacitor, a body size of 0402 is recommended. *Figure 7* shows the AC coupling capacitor placement in an AC test circuit.

Input Equalization

Each differential input of the DS42BR400 has a fixed equalizer front-end stage. It is designed to provide fixed equalization for short board traces with transmission losses of approximately 5 dB between 375 MHz to 1.875 GHz. Programmable de-emphasis together with input equalization ensures an acceptable eye opening for a 40-inch FR-4 backplane.

The <u>differential</u> input equalizer for inputs on Channel A and inputs on Channel B can be bypassed by using <u>EQA</u> and <u>EQB</u>, respectively. By default, the equalizers are internally pulled high and disabled. Therefore, <u>EQA</u> and <u>EQB</u> must be asserted LOW to enable equalization.

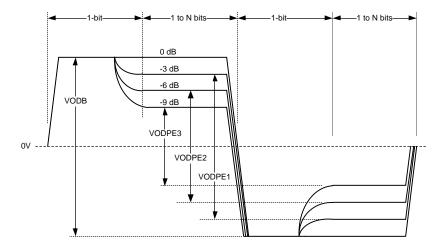


Figure 2. Driver De-Emphasis Differential Waveform (showing all 4 de-emphasis steps)



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

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Absolute Maximum Ratings(1)(2)

Supply Voltage (V _{CC})		-0.3V to 4V
CMOS/TTL Input Voltage		-0.3V to (V _{CC} +0.3V)
CML Input/Output Voltage	-0.3V to (V _{CC} +0.3V)	
Junction Temperature	+150°C	
Storage Temperature	−65°C to +150°C	
Lead Temperature Soldering, 4 sec	+260°C	
Thermal Resistance, θ_{JA}		22.3°C/W
Thermal Resistance, θ_{JC}		3.2°C/W
Thermal Resistance, Φ _{JB}		10.3°C/W
ESD Ratings ⁽³⁾	НВМ	6kV
	CDM	1kV
	MM	350V

^{(1) &}quot;Absolute Maximum Ratings" indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional. For ensured specifications and the test conditions, see the Electrical Characteristics Tables. Operation of the device beyond the maximum Operating Ratings is not recommended.

Recommended Operating Ratings

	Min	Тур	Max	Units
Supply Voltage (V _{CC} -GND)	3.135	3.3	3.465	V
Supply Noise Amplitude 10 Hz to 2 GHz			100	mV_{PP}
Ambient Temperature	-40		+85	°C
Case Temperature			100	°C

⁽²⁾ If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.

⁽³⁾ ESD tests conform to the following standards: Human Body Model (HBM) applicable standard: MIL-STD-883, Method 3015.7Machine Model (MM) applicable standard: JESD22-A115-A (ESD MM std. of JEDEC)Field -Induced Charge Device Model (CDM) applicable standard: JESD22-C101-C (ESD FICDM std. of JEDEC)



Electrical Characteristics (1)(2)

Over recommended operating supply and temperature ranges unless otherwise specified.

	Parameter	Test Conditions	Min	Typ (3)	Max	Units
LVCMOS	DC SPECIFICATIONS			I.	1	
V _{IH}	High Level Input Voltage		2.0		V _{CC} +0.3	V
V_{IL}	Low Level Input Voltage		-0.3		0.8	V
I _{IH}	High Level Input Current	$V_{IN} = V_{CC}$	-10		10	μΑ
I _{IL}	Low Level Input Current	V _{IN} = GND	75	94	124	μΑ
R_{PU}	Pull-High Resistance			35		kΩ
RECEIVE	R SPECIFICATIONS					
V_{ID}	Differential Input Voltage Range	AC Coupled Differential Signal. Below 1.25 Gb/s At 1.25 Gbps–3.125 Gbps Above 3.125 Gbps This parameter is not production tested.	100 100 100		1750 1560 1200	mV_{P-P} mV_{P-P}
V_{ICM}	Common Mode Voltage at Receiver Inputs	Measured at receiver inputs reference to ground.		1.3		V
R _{ITD}	Input Differential Termination	On-chip differential termination between IN+ or INSeeFigure 8	84	100	116	Ω
DRIVER S	SPECIFICATIONS					
VODB	Output Differential Voltage Swing without De-Emphasis	$R_L = 100\Omega \pm 1\%$ $PreA_L = 0$; $PreA_L = 0$ $PreB_L = 0$; $PreB_L = 0$ $PreB_L = 0$; $PreB_L = 0$ $PreB_L = 0$; $PreB_L = 0$ $PreB_L = $	1000	1200	1400	mV_{P-P}
V _{PE}	Output De-Emphasis Voltage Ratio 20*log(VODPE/VODB)	$R_L = 100\Omega \pm 1\%$ Running K28.7 pattern at 4.25 Gbps $PreX_{1}[1:0] = 00$ $PreX_{1}[1:0] = 01$ $PreX_{1}[1:0] = 10$ $PreX_{1}[1:0] = 11$ X = A/B channel de-emphasis drivers See(Figure 2/ Figure 7)		0 -3 -6 -9		dB dB dB dB
t _{PE}	De-Emphasis Width	Tested at -9 dB de-emphasis level, PreX[1:0] = 11 X = A/B channel de-emphasis drivers See Figure 6 on measurement condition.	125	200	250	ps
R _{OTSE}	Output Termination	On-chip termination from OUT+ or OUT- to V _{CC}	42	50	58	Ω
R _{OTD}	Output Differential Termination	On-chip differential termination between OUT+ and OUT-		100		Ω
ΔR_{OTSE}	Mis-Match in Output Termination Resistors	Mis-match in output termination resistors			5	%
V _{OCM}	Output Common Mode Voltage			2.7		V
POWER I	DISSIPATION					
P _D	Power Dissipation	V_{DD} = 3.465V All outputs terminated by 100 Ω ±1%. PreB_[1:0] = 0, PreA_[1:0] = 0 Running PRBS 2 ⁷ -1 pattern at 4.25 Gbps			1.3	W

⁽¹⁾ IN+ and IN- are generic names that refer to one of the many pairs of complementary inputs of the DS42BR400. OUT+ and OUT- are generic names that refer to one of the many pairs of the complementary outputs of the DS42BR400. Differential input voltage V_{ID} is defined as |IN+ - IN-|. Differential output voltage V_{OD} is defined as |OUT+ - OUT-|.

⁽²⁾ K28.7 pattern is a 10-bit repeating pattern of K28.7 code group {001111 1000}K28.5 pattern is a 20-bit repeating pattern of +K28.5 and -K28.5 code groups {110000 0101 001111 1010}

⁽³⁾ Typical specifications are at TA=25 C, and represent most likely parametric norms at the time of product characterization. The typical specifications are not ensured.



Electrical Characteristics(1)(2) (continued)

Over recommended operating supply and temperature ranges unless otherwise specified.

	Parameter	Test Conditions	Min	Typ (3)	Max	Units
AC CHA	ARACTERISTICS					
t _R Differential Low to High Transition Time		Measured with a clock-like pattern at 4.25 Gbps, between 20% and 80% of the differential output		80		ps
t _F	Differential High to Low Transition Time	voltage. De-emphasis disabled. Transition time is measured with the fixture shown in Figure 7 adjusted to reflect the transition time at the output pins.		80		ps
t _{PLH}	Differential Low to High Propagation Delay	Measured at 50% differential voltage from input to output.			1	ns
t _{PHL}	Differential High to Low Propagation Delay				1	ns
t _{SKP}	Pulse Skew	t _{PHL} -t _{PLH}			20	ps
t _{SKO}	Output Skew ⁽⁴⁾	Difference in propagation delay between channels on the same part (Channel-to-Channel Skew) ⁽⁴⁾			100	ps
t _{SKPP}	Part-to-Part Skew ⁽⁴⁾	Difference in propagation delay between devices across all channels operating under identical conditions			165	ps
t _{LB}	Loopback Delay Time	Delay from enabling loopback mode to signals appearing at the differential outputs SeeFigure 5			4	ns
RJ	Device Random Jitter ⁽⁵⁾	At 0.25 Gbps At 1.5 Gbps At 4.25 Gbps Alternating-10 pattern. De-emphasis disabled. See(Figure 7)			2 2 2	ps rms ps rms ps rms
DJ	Device Deterministic Jitter ⁽⁶⁾	At 0.25 Mbps, PRBS7 pattern At 1.5 Gbps, K28.5 pattern At 4.25 Gbps, K28.5 pattern At 4.25 Gbps, PRBS7 pattern De-emphasis disabled. See(Figure 7)			25 25 25 25 25	ps pp ps pp ps pp ps pp
DR	Data Rate ⁽⁷⁾	Alternating-10 pattern	0.25		4.25	Gbps

- (4) t_{SKO} is the magnitude difference in propagation delays between all data paths on one device. This is channel-to-channel skew. t_{SKPP} is the worst case difference in propagation delay across multiple devices on all channels and operating under identical conditions. For example, for two devices operating under the same conditions, t_{SKPP} is the magnitude difference between the shortest propagation delay measurement on one device to the longest propagation delay measurement on another device.
- Device output random jitter is a measurement of random jitter contributed by the device. It is derived by the equation SQRT[(RJ_{OUT})² (RJ_{IN})²], where RJ_{OUT} is the total random jitter measured at the output of the device in ps(rms), RJ_{IN} is the random jitter of the pattern generator driving the device. Below 400 Mbps, system jitter and device jitter could not be separated. The 250 Mbps specification includes system random jitter. Please see Figure 7 for the AC test circuit.
- Device output deterministic jitter is a measurement of the deterministic jitter contribution from the device. It is derived by the equation (DJ_{OUT} - DJ_{IN}), where DJ_{OUT} is the total peak-to-peak deterministic jitter measured at the output of the device in ps(p-p). DJ_{IN} is the peak-to-peak deterministic jitter at the input of the test board. Please see Figure 7 for the AC test circuit.

Product Folder Links: DS42BR400

This parameter is specified by design and/or characterization and is not tested in production.



TIMING DIAGRAMS

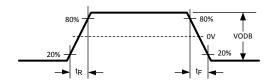


Figure 3. Driver Output Transition Time

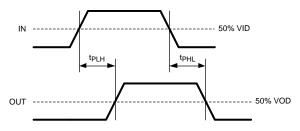


Figure 4. Propagation Delay

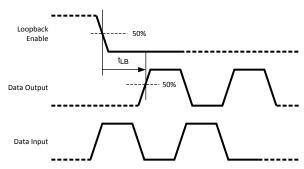


Figure 5. Loopback Delay Timing

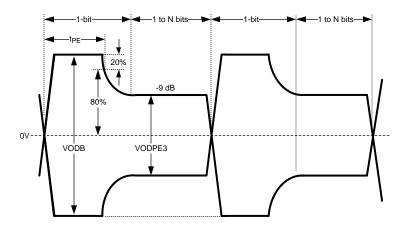


Figure 6. Output De-Emphasis Duration



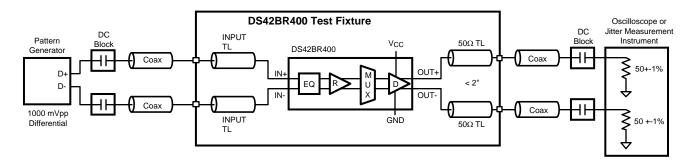


Figure 7. AC Test Circuit

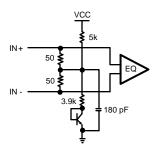


Figure 8. Receiver Input Termination





REVISION HISTORY

Cł	nanges from Revision I (April 2013) to Revision J	Pag	
•	Changed layout of National Data Sheet to TI format		11

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PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
						(4)	(5)		
DS42BR400TSQ/NOPB	Active	Production	WQFN (NKA) 60	250 SMALL T&R	Yes	SN	Level-3-260C-168 HR	-40 to 85	DS42BR400 TSQ
DS42BR400TSQ/NOPB.A	Active	Production	WQFN (NKA) 60	250 SMALL T&R	Yes	SN	Level-3-260C-168 HR	-40 to 85	DS42BR400 TSQ

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

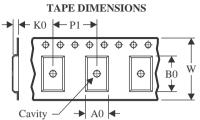
⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

PACKAGE MATERIALS INFORMATION

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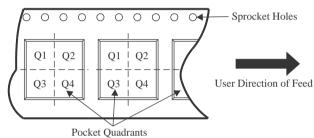
TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

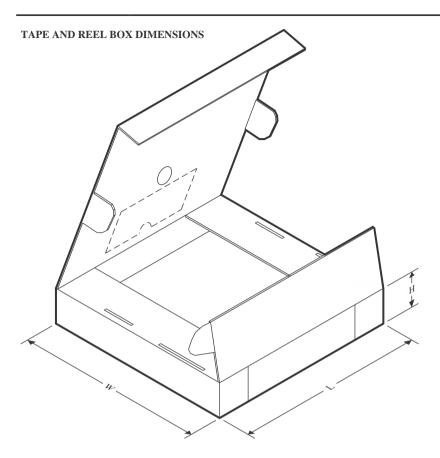


*All dimensions are nominal

Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DS42BR400TSQ/NOPB	WQFN	NKA	60	250	178.0	16.4	9.3	9.3	1.3	12.0	16.0	Q1

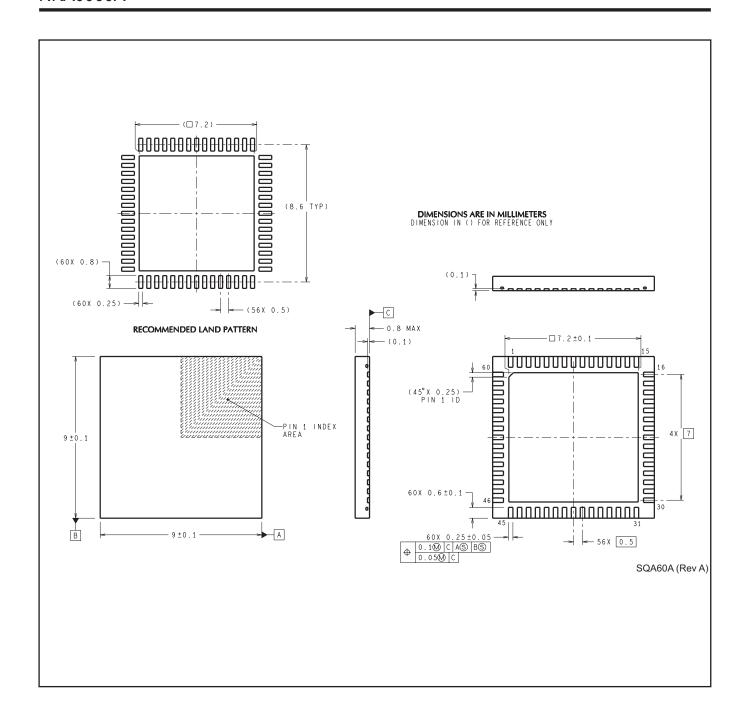
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*All dimensions are nominal

	Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
I	DS42BR400TSQ/NOPB	WQFN	NKA	60	250	208.0	191.0	35.0





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